SKKT 42, SKKT 42B, SKKH 42

SEMIPACK® 1

Thyristor / Diode Modules

SKKT 42

SKKT 42B

SKKH 42

Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

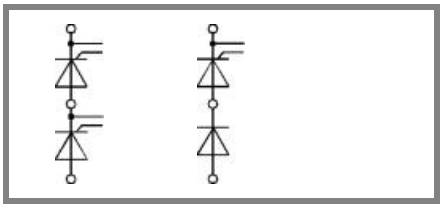
Typical Applications*

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

V_{RSM} V	V_{RRM}, V_{DRM} V	I_{TRMS} = 75 A (maximum value for continuous operation) I_{TAV} = 40 A (sin. 180; T_c = 85 °C)		
900	800	SKKT 42/08E	SKKT 42B08E	SKKH 42/08E
1300	1200	SKKT 42/12E	SKKT 42B12E	SKKH 42/12E
1500	1400	SKKT 42/14E	SKKT 42B14E	SKKH 42/14E
1700	1600	SKKT 42/16E	SKKT 42B16E	SKKH 42/16E
1900	1800	SKKT 42/18E	SKKT 42B18E	SKKH 42/18E

Symbol	Conditions	Values	Units
I_{TAV}	sin. 180; T_c = 85 (100) °C;	40 (28)	A
I_D	P3/180; T_a = 45 °C; B2 / B6	50 / 60	A
	P3/180F; T_a = 35 °C; B2 / B6	85 /110	A
I_{RMS}	P3/180F; T_a = 35 °C; W1 / W3	110 / 3 * 85	A
I_{TSM}	T_{vj} = 25 °C; 10 ms	1000	A
	T_{vj} = 125 °C; 10 ms	850	A
i²t	T_{vj} = 25 °C; 8,3 ... 10 ms	5000	A²s
	T_{vj} = 125 °C; 8,3 ... 10 ms	3600	A²s
V_T	T_{vj} = 25 °C; I_T = 200 A	max. 1,95	V
$V_{T(TO)}$	T_{vj} = 125 °C	max. 1	V
r_T	T_{vj} = 125 °C	max. 4,5	mΩ
I_{DD}; I_{RD}	T_{vj} = 125 °C; V_{RD} = V_{RRM}; V_{DD} = V_{DRM}	max. 15	mA
t_{gd}	T_{vj} = 25 °C; I_G = 1 A; di_G/dt = 1 A/µs	1	µs
t_{gr}	V_D = 0,67 * V_{DRM}	2	µs
$(di/dt)_{cr}$	T_{vj} = 125 °C	max. 150	A/µs
$(dv/dt)_{cr}$	T_{vj} = 125 °C	max. 1000	V/µs
t_q	T_{vj} = 125 °C ,	80	µs
I_H	T_{vj} = 25 °C; typ. / max.	150 / 250	mA
I_L	T_{vj} = 25 °C; R_G = 33 Ω; typ. / max.	300 / 600	mA
V_{GT}	T_{vj} = 25 °C; d.c.	min. 3	V
I_{GT}	T_{vj} = 25 °C; d.c.	min. 150	mA
V_{GD}	T_{vj} = 125 °C; d.c.	max. 0,25	V
I_{GD}	T_{vj} = 125 °C; d.c.	max. 6	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,65 / 0,33	K/W
$R_{th(j-c)}$	sin. 180; per thyristor / per module	0,69 / 0,35	K/W
$R_{th(j-c)}$	rec. 120; per thyristor / per module	0,73 / 0,37	K/W
$R_{th(c-s)}$	per thyristor / per module	0,2 / 0,1	K/W
T_{vj}		- 40 ... + 125	°C
T_{stg}		- 40 ... + 125	°C
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 %[1)]	Nm
M_t	to terminals	3 ± 15 %	Nm
a		5 * 9,81	m/s²
m	approx.	95	g
Case	SKKT	A 46	
	SKKT ...B	A 48	
	SKKH	A 47	



SKKT SKKH

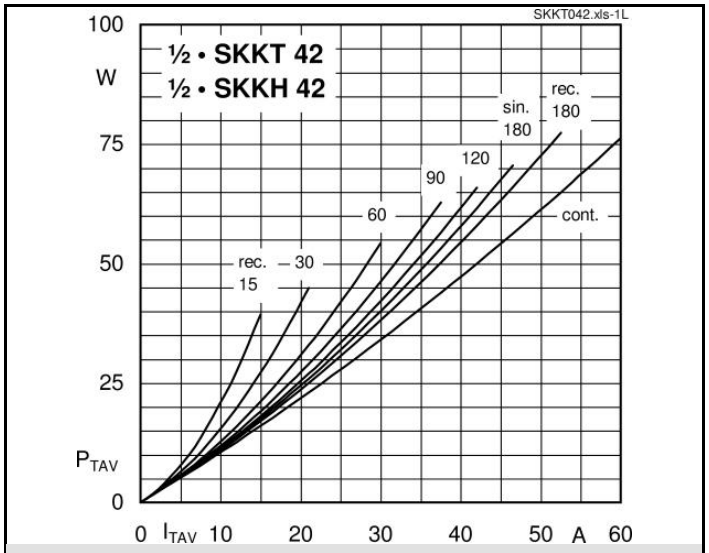


Fig. 1L Power dissipation per thyristor vs. on-state current

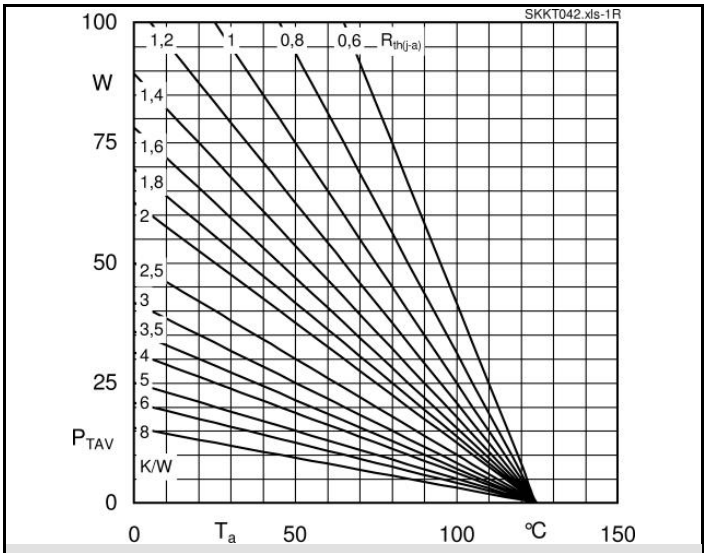


Fig. 1R Power dissipation per thyristor vs. ambient temp.

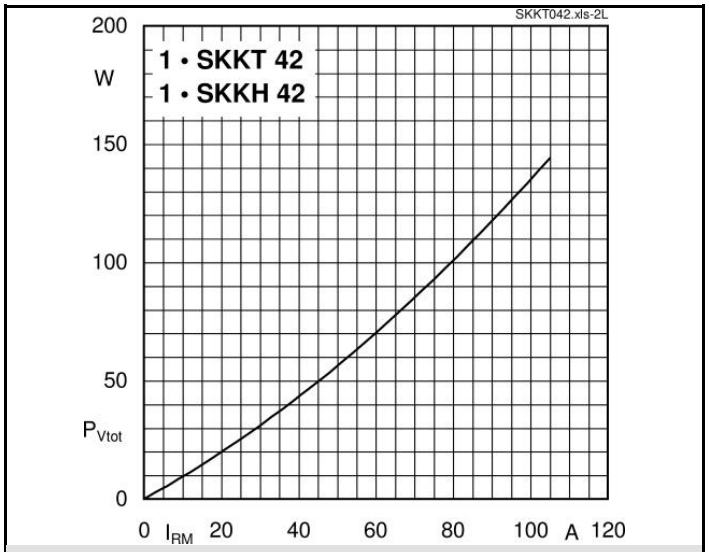


Fig. 2L Power dissipation per module vs. rms current

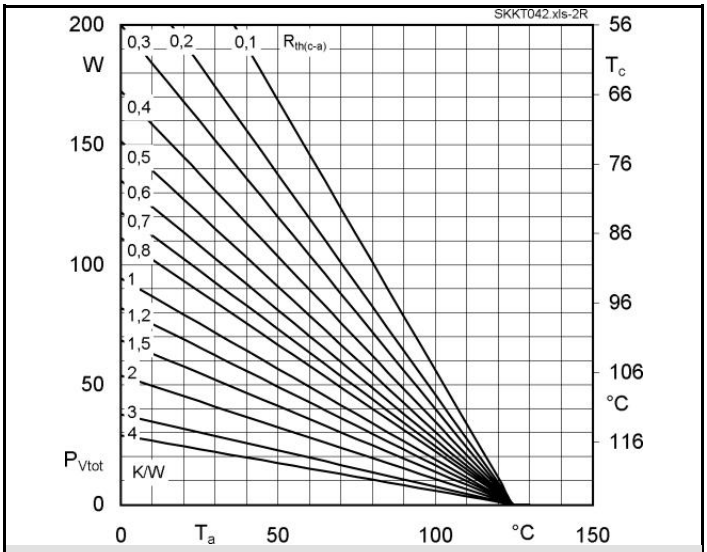


Fig. 2R Power dissipation per module vs. case temp.

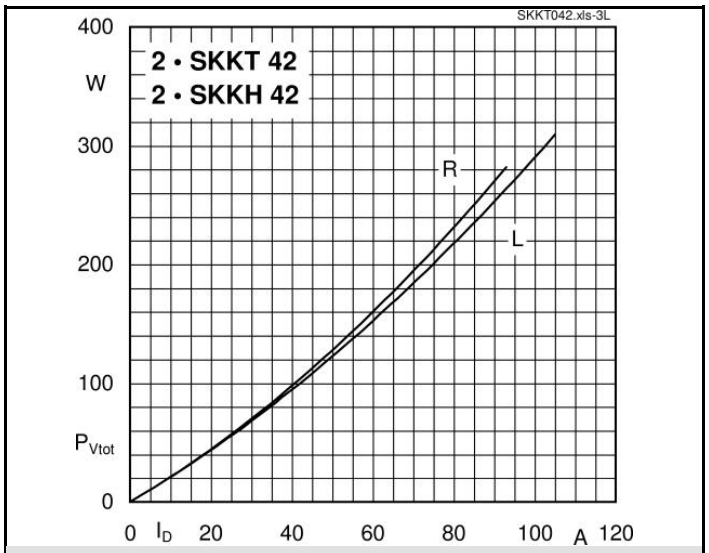


Fig. 3L Power dissipation of two modules vs. direct current

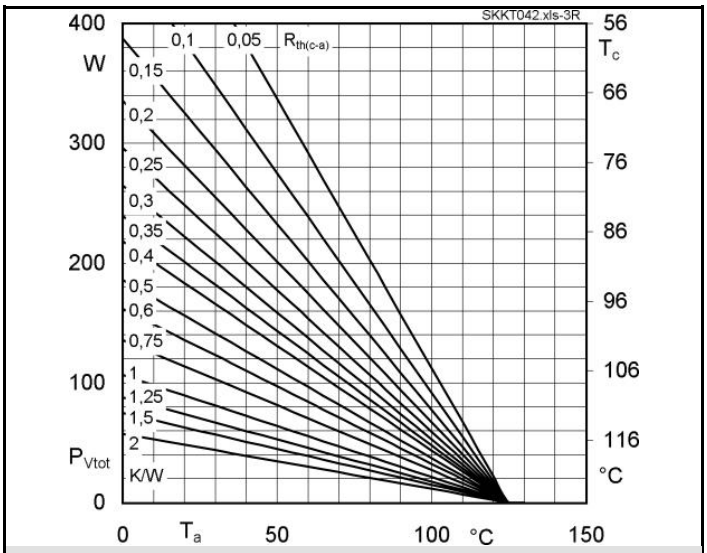


Fig. 3R Power dissipation of two modules vs. case temp.

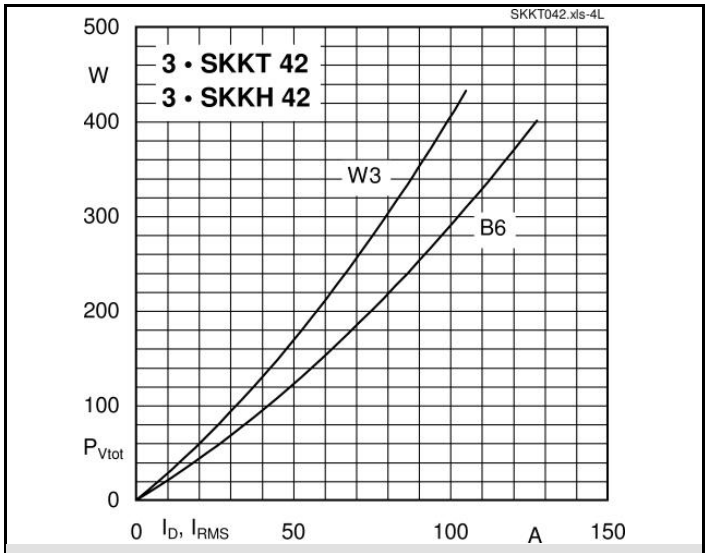


Fig. 4L Power dissipation of three modules vs. direct and rms current

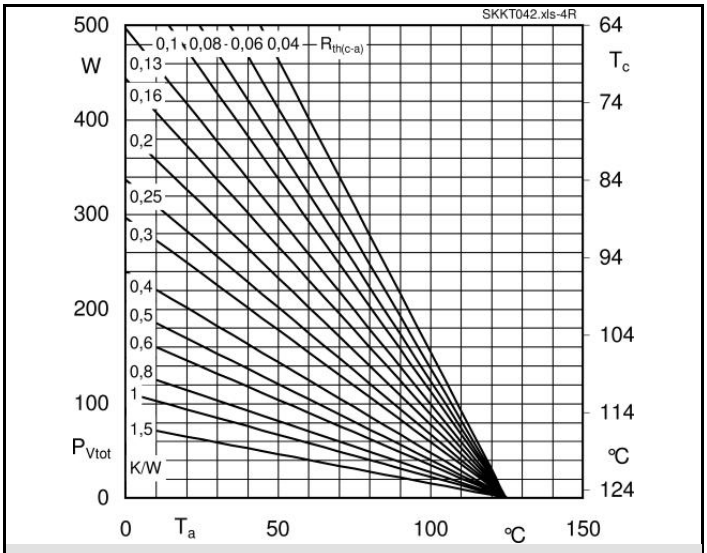


Fig. 4R Power dissipation of three modules vs. case temp.

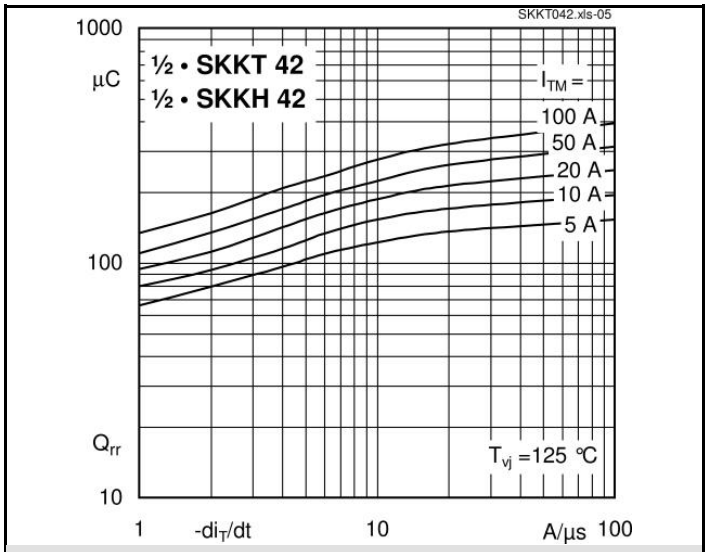


Fig. 5 Recovered charge vs. current decrease

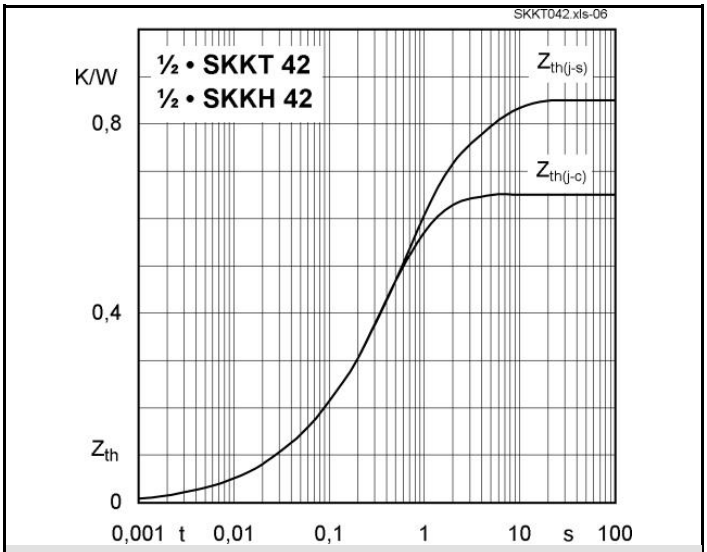


Fig. 6 Transient thermal impedance vs. time

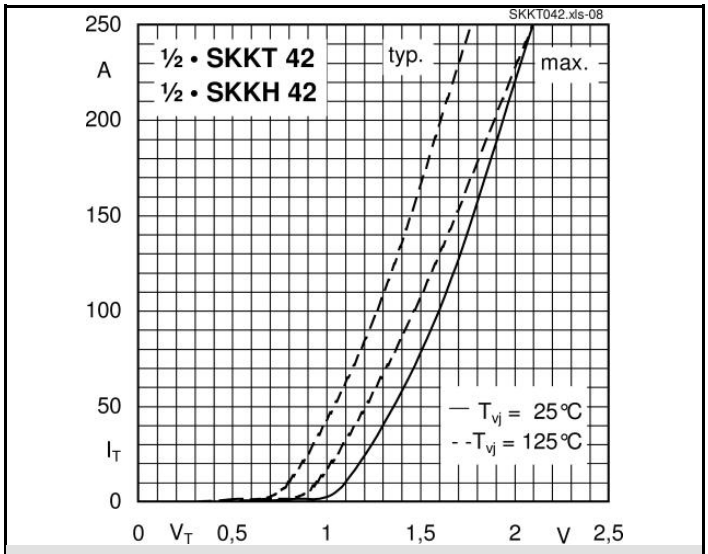


Fig. 7 On-state characteristics

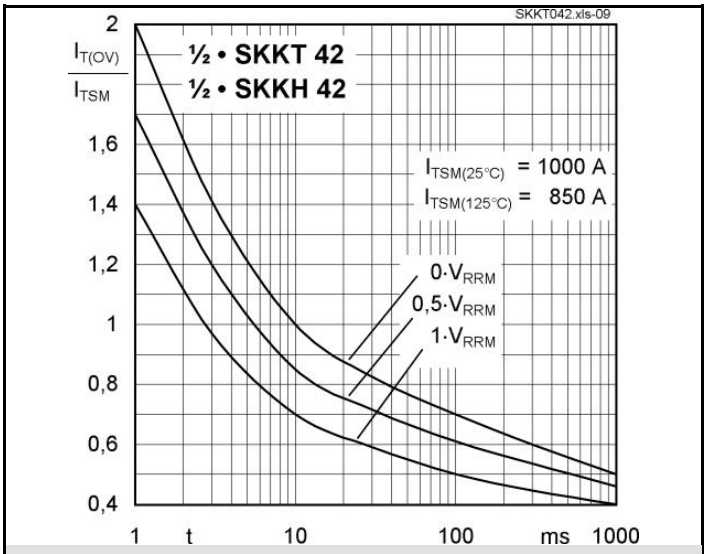


Fig. 8 Surge overload current vs. time

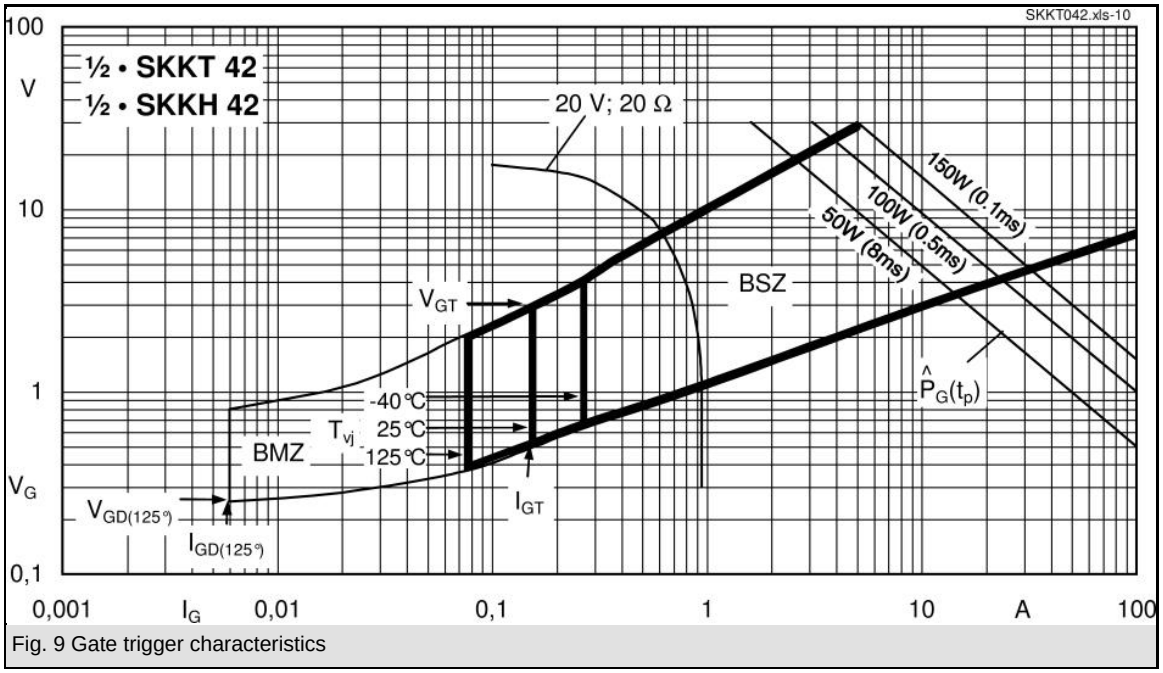
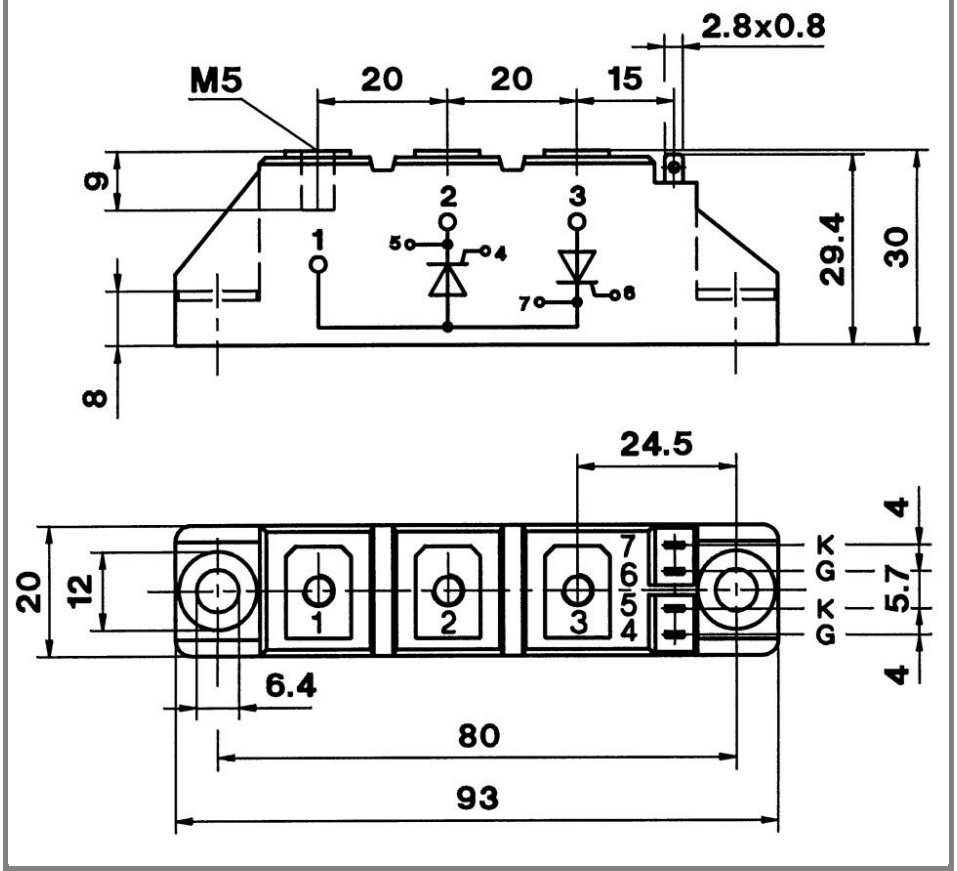
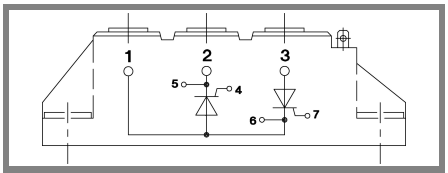


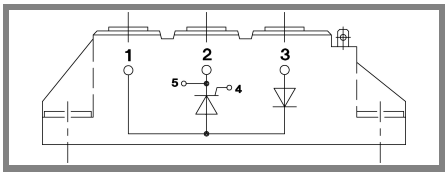
Fig. 9 Gate trigger characteristics

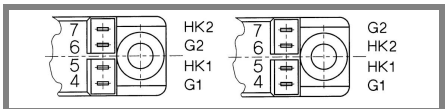
Dimensions in mm



Case A 46 (SKKT)


Case A 48 SKKT...B


Case A 47 SKKH



SKKT SKKT ...B

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.

